

# BY251P thru BY255P

#### **Vishay General Semiconductor**

# **General Purpose Plastic Rectifier**

#### **Major Ratings and Characteristics**

| I <sub>F(AV)</sub>  | 3.0 A           |
|---------------------|-----------------|
| V <sub>RRM</sub>    | 200 V to 1300 V |
| I <sub>FSM</sub>    | 150 A           |
| I <sub>R</sub>      | 5.0 µA          |
| V <sub>F</sub>      | 1.1 V           |
| T <sub>j</sub> max. | 150 °C          |



#### Features

- Low forward voltage drop
- Low leakage current,  $I_R$  less than 0.1  $\mu A$
- High forward surge capability
- Solder Dip 260 °C, 40 seconds

### **Typical Applications**

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes application.

(Note: These devices are not Q101 qualified. Therefore, the devices specified in this datasheet have not been designed for use in automotive or Hi-Rel applications.)

#### **Maximum Ratings**

| (T <sub>A</sub> = 25 °C unless otherwise noted)                                      |                    |               |        |        |        |        |      |
|--|--------------------|---------------|--------|--------|--------|--------|------|
| Parameter  | Symbol             | BY251P        | BY252P | BY253P | BY254P | BY255P | Unit |
| Maximum repetitive peak reverse voltage  | V <sub>RRM</sub>   | 200           | 400    | 600    | 800    | 1300   | V    |
| Maximum RMS voltage  | V <sub>RMS</sub>   | 140           | 280    | 420    | 560    | 910    | V    |
| Maximum DC blocking voltage  | V <sub>DC</sub>    | 200           | 400    | 600    | 800    | 1300   | V    |
| Maximum average forward rectified current 10 mm lead length                          | I <sub>F(AV)</sub> | 3.0           |        |        |        |        | А    |
| Peak forward surge current 10 ms single half sine-wave<br>superimposed on rated load | I <sub>FSM</sub>   | 150           |        |        |        |        | А    |
| Maximum full load reverse current, full cycle average 10 mm lead length              | I <sub>R(AV)</sub> | 100           |        |        |        |        | μA   |
| Operating junction and storage temperature range                                     | $T_J, T_{STG}$     | - 55 to + 150 |        |        |        |        | °C   |

## Mechanical Data

**Case:** DO-201AD, molded epoxy body Epoxy meets UL-94V-0 Flammability rating **Terminals:** Matte tin plated (E3 Suffix) leads, solderable per J-STD-002B and JESD22-B102D **Polarity:** Color band denotes cathode end

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#### **Electrical Characteristics**

(T<sub>A</sub> = 25 °C unless otherwise noted)

| Parameter  | Test condition  | Symbol          | BY251P | BY252P | BY253P | BY254P | BY255P | Unit |
|--|---|-----------------|--------|--------|--------|--------|--------|------|
| Maximum instantaneous<br>forward voltage             | at 3.0 A  | V <sub>F</sub>  |        | 1.1    |        |        |        | V    |
| Maximum reverse current at rated DC blocking voltage | T <sub>A</sub> = 25 °C  | ۱ <sub>R</sub>  | 5.0    |        |        |        | μΑ     |      |
| Typical reverse recovery time                        | I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 V,<br>I <sub>rr</sub> = 0.25 A | t <sub>rr</sub> | 3.0    |        |        | μs     |        |      |
| Typical junction capacitance                         | at 4.0 V, 1 MHz   | CJ              |        |        | 40     |        |        | pF   |

### **Thermal Characteristics**

(T<sub>A</sub> = 25 °C unless otherwise noted)

| Parameter                                 | Symbol                               | BY251P   | BY252P | BY253P | BY254P | BY255P | Unit |
|---|--------------------------------------|----------|--------|--------|--------|--------|------|
| Typical thermal resistance <sup>(1)</sup> | R <sub>θJA</sub><br>R <sub>θJL</sub> | 20<br>10 |        |        |        |        | °C/W |

Notes:

(1) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5 mm) lead length, P.C.B. mounted

### **Ratings and Characteristics Curves**

(T<sub>A</sub> = 25 °C unless otherwise noted)

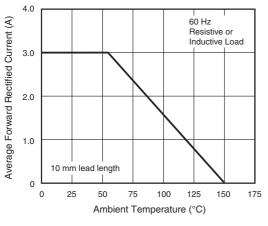


Figure 1. Forward Current Derating Curve

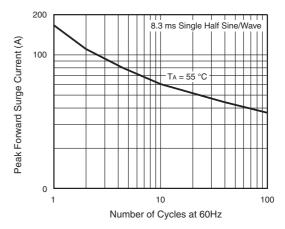


Figure 2. Maximum Non-repetitive Peak Forward Surge Current



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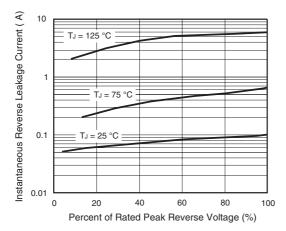


Figure 3. Maximum Non-repetitive Peak Forward Surge Current

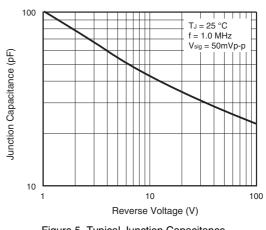


Figure 5. Typical Junction Capacitance

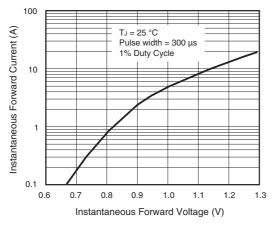
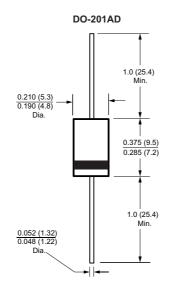


Figure 4. Typical Instantaneous Forward Characteristics

## Package outline dimensions in inches (millimeters)





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